## DT01 Rec'd PCT/PTC 2 8 FEB 2005 IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Ellison et al.

Attorney Docket: 35947-213490

Application No.: U.S. National Phase of

Art Unit: to be assigned

PCT/SE2003/001309

Filed: herewith

Examiner: to be assigned

Title: LIGHTLY DOPED SILICON CARBIDE WAFER AND USE THEREOF IN HIGH

**POWER DEVICES** 

## PRELIMINARY AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

Sir:

Prior to examination, please amend the above-identified application as follows: